# TOSHIBA

**Discrete Semiconductors** 

**Field Effect Transistor** 

Silicon N Channel MOS Type (π-MOS II.5)

High Speed, High Current DC-DC Converter,

## **Relay Drive and Motor Drive Applications**

#### Features

- Low Drain-Source ON Resistance
- R<sub>DS(ON)</sub> = 1.1Ω (Typ.)
- High Forward Transfer Admittance
- $|Y_{fs}| = 4.0S$  (Typ.)
- Low Leakage Current
- $I_{DSS} = 300 \mu A$  (Max.) @  $V_{DS} = 720 V$
- Enhancement-Mode
  - $V_{th}$  = 1.5  $\sim$  3.5V @  $V_{DS}$  = 10V,  $I_{D}$  = 1mA

#### Absolute Maximum Ratings (Ta = 25°C)

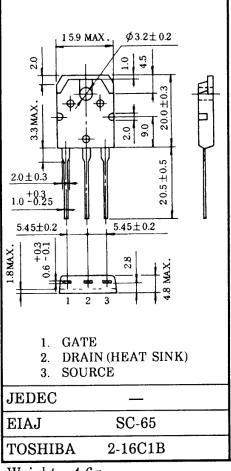
CHARACTERISTIC		SYMBOL	RATING	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	900	V
Drain-Gate Voltage ( $R_{GS} = 20k\Omega$ )		V <sub>DGR</sub>	900	V
Gate-Source Voltage		V <sub>GSS</sub>	±30	V
Drain Current	DC	I <sub>D</sub>	9	А
	Pulse	I <sub>DP</sub>	27	
Drain Power Dissipation (Tc = 25°C)		PD	150	W
Channel Temperature		T <sub>ch</sub>	150	°C
Storage Temperature Range		T <sub>stg</sub>	-55 ~ 150	°C



CHARACTERISTIC	SYMBOL	MAX.	UNIT
Thermal Resistance, Channel to Case	R <sub>th(ch-c)</sub>	0.833	°C/W
Thermal Resistance, Channel to Ambient	R <sub>th(ch-a)</sub>	50	°C/W

This transistor is an electrostatic sensitive device. Please handle with care.





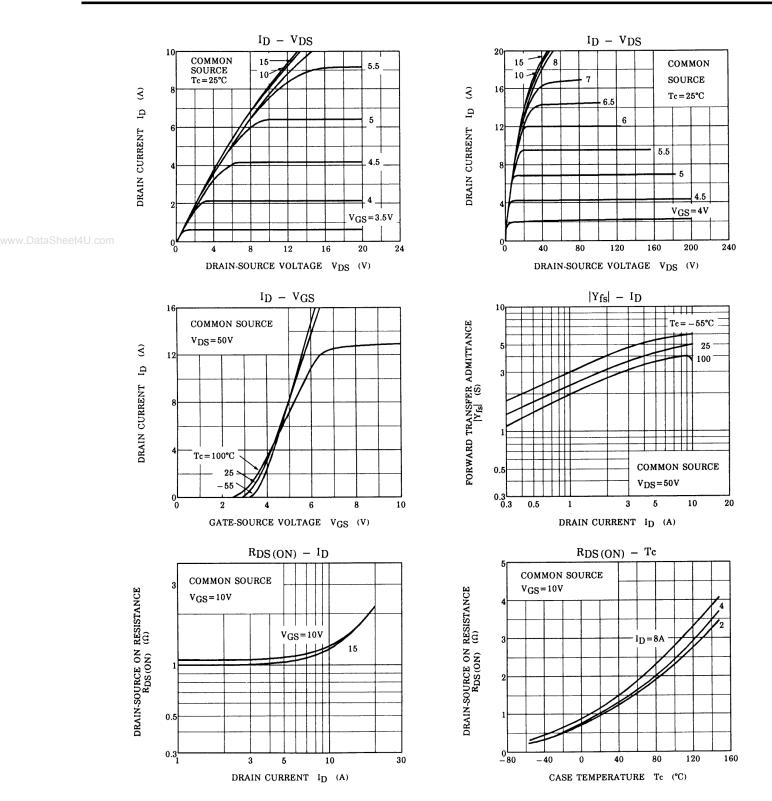
Weight: 4.6g

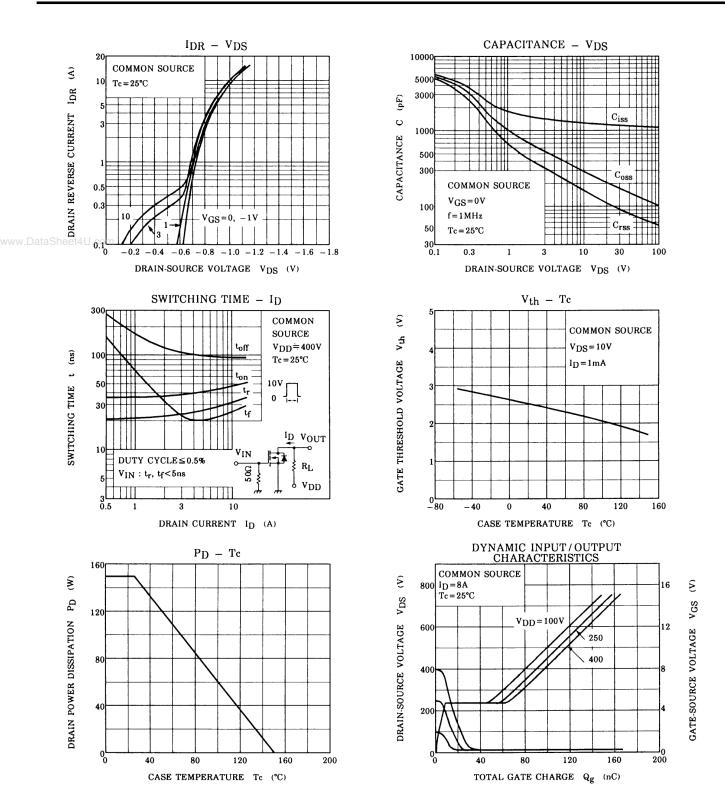
## Electrical Characteristics (Ta = 25°C)

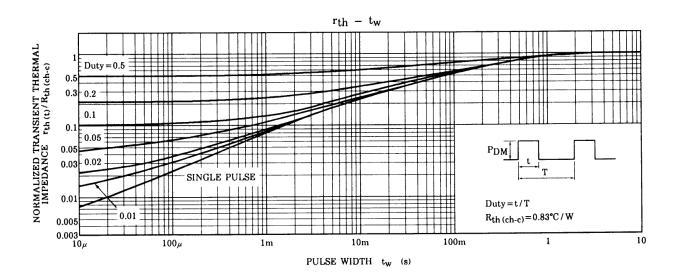
CHAR	ACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage C	urrent	I <sub>GSS</sub>	$V_{GS} = \pm 25V, V_{DS} = 0V$	-	-	±100	nA
Drain Cut-off C	urrent	I <sub>DSS</sub>	$V_{DS} = 720V, V_{GS} = 0V$	-	-	300	μA
Drain-Source B	reakdown Voltage	V(BR) DSS	$I_D = 10 \text{mA}, V_{GS} = 0 \text{V}$	900	-	-	V
Gate Threshold	Voltage	V <sub>th</sub>	$V_{DS} = 10V$ , $I_D = 1mA$	1.5	-	3.5	V
Drain-Source O	N Resistance	R <sub>DS (ON)</sub>	$I_D = 4A, V_{GS} = 10V$	-	1.1	1.4	Ω
Forward Transfe	er Admittance	Y <sub>fs</sub>	$V_{DS} = 20V$ , $I_D = 4A$	2.0	4.0	-	S
Input Capacitan	се	C <sub>iss</sub>			1300	1800	рF
Reverse Transfe	Reverse Transfer Capacitance		$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz	-	100	150	
Output Capacita	Output Capacitance			-	180	260	
	Rise Time	t <sub>r</sub>		-	25	50	
Switching	Turn-on Time	t <sub>on</sub>	$v_{\text{GS}_{0V}}^{10V} \prod \overset{\text{ID}=4A}{\downarrow} v_{\text{OUT}}$	-	40	80	
Time	Fall Time	t <sub>f</sub>	$\begin{array}{c c} & & & \\ & & & & \\ & & & \\ & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\$	-	20	40	ns
	Turn-off Time	t <sub>off</sub>		-	100	200	
			$V_{IN}$ : t <sub>r</sub> , t <sub>f</sub> <5ns, $V_{DD}$ =400V Duty $\leq 1\%$ , t <sub>w</sub> =10 $\mu$ s				
	Total Gate Charge (Gate-Source Plus Gate-Drain)		$V_{DD} = 400V, V_{GS} = 10V,$	-	120	240	
Gate-Source Ch	Gate-Source Charge		$-I_{\rm D} = 9A$	-	70	-	nC
Gate-Drain ("M	iller") Charge	Q <sub>gd</sub>		-	50	-	

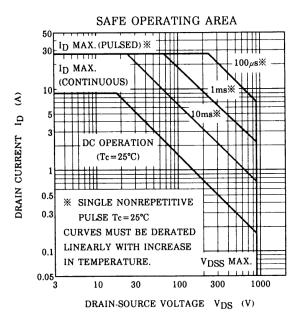
### Source-Drain Diode Ratings and Characteristics (Ta = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Continuous Drain Reverse Current	I <sub>DR</sub>	-	-	-	9	А
Pulse Drain Reverse Current	I <sub>DRP</sub>	-	-	-	27	А
Diode Forward Voltage	V <sub>DSF</sub>	$I_{DR} = 9A$ , $V_{GS} = 0V$	-	-	-2.0	V









Notes

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